



P-Channel 20 V (D-S) MOSFET

| PRODUCT SUMMARY | | | |
|---------------------|------------------------------------|---------------------------------|-----------------------|
| V _{DS} (V) | R _{DS(on)} (Ω) | I _D (A) ^a | Q _g (Typ.) |
| - 20 | 0.064 at V _{GS} = - 4.5 V | - 2.0 ^e | 7.6 nC |
| | 0.085 at V _{GS} = - 2.5 V | - 2.0 ^e | |
| | 0.110 at V _{GS} = - 1.8 V | - 2.0 ^e | |
| | 0.165 at V _{GS} = - 1.5 V | - 0.5 | |

FEATURES

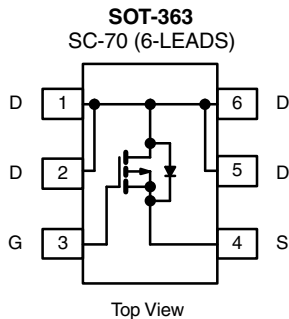
- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFET
- 100 % R_g Tested
- Typical ESD Performance 2000 V
- Built in ESD Protection with Zener Diode
- Compliant to RoHS Directive 2002/95/EC



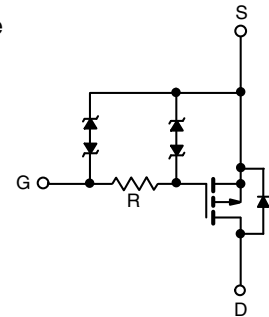
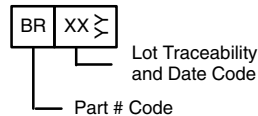
RoHS
COMPLIANT
HALOGEN
FREE

APPLICATIONS

- Load Switch for Portable Devices
 - Cellular Phone
 - DSC
 - Portable Game Console
 - MP3
 - GPS



Marking Code



P-Channel MOSFET

Ordering Information: Si1427EDH-T1-GE3 (Lead (Pb)-free and Halogen-free)

| ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted) | | | |
|---|-----------------------------------|------------------------|--------------------------|
| Parameter | Symbol | Limit | Unit |
| Drain-Source Voltage | V _{DS} | - 20 | V |
| Gate-Source Voltage | V _{GS} | ± 8 | |
| Continuous Drain Current (T _J = 150 °C) | I _D | T _C = 25 °C | - 2.0 ^{a, e} |
| | | T _C = 70 °C | - 2.0 ^e |
| | | T _A = 25 °C | - 2.0 ^{b, c, e} |
| | | T _A = 70 °C | - 2.0 ^{b, c, e} |
| Pulsed Drain Current | I _{DM} | - 8 | A |
| Continuous Source-Drain Diode Current | I _S | T _C = 25 °C | |
| | | T _A = 25 °C | - 1.3 ^{b, c} |
| Maximum Power Dissipation | P _D | T _C = 25 °C | 2.8 |
| | | T _C = 70 °C | 1.8 |
| | | T _A = 25 °C | 1.56 ^{b, c} |
| | | T _A = 70 °C | 1 ^{b, c} |
| Operating Junction and Storage Temperature Range | T _J , T _{stg} | - 55 to 150 | °C |
| Soldering Recommendations (Peak Temperature) ^{d, e} | | 260 | |

| THERMAL RESISTANCE RATINGS | | | | | |
|---|--------------|-------------------|---------|---------|------|
| Parameter | | Symbol | Typical | Maximum | Unit |
| Maximum Junction-to-Ambient ^{b, d} | t ≤ 5 s | R _{thJA} | 60 | 80 | °C/W |
| Maximum Junction-to-Foot (Drain) | Steady State | R _{thJF} | 34 | 45 | |

Notes:

- T_C = 25 °C.
- Surface mounted on 1" x 1" FR4 board.
- t = 5 s.
- Maximum under steady state conditions is 125 °C/W.
- Package limited.



| SPECIFICATIONS ($T_J = 25\text{ }^\circ\text{C}$, unless otherwise noted) | | | | | | | |
|---|-------------------------|---|----------|--|-----------|---------------|-----|
| Parameter | Symbol | Test Conditions | Min. | Typ. | Max. | Unit | |
| Static | | | | | | | |
| Drain-Source Breakdown Voltage | V_{DS} | $V_{GS} = 0\text{ V}, I_D = -250\text{ }\mu\text{A}$ | -20 | | | V | |
| V_{DS} Temperature Coefficient | $\Delta V_{DS}/T_J$ | $I_D = -250\text{ }\mu\text{A}$ | | -13 | | mV/°C | |
| $V_{GS(th)}$ Temperature Coefficient | $\Delta V_{GS(th)}/T_J$ | | | 2.5 | | | |
| Gate-Source Threshold Voltage | $V_{GS(th)}$ | $V_{DS} = V_{GS}, I_D = -250\text{ }\mu\text{A}$ | -0.4 | | -1 | V | |
| Gate-Source Leakage | I_{GSS} | $V_{DS} = 0\text{ V}, V_{GS} = \pm 8\text{ V}$ | | | ± 6 | μA | |
| | | $V_{DS} = 0\text{ V}, V_{GS} = \pm 4.5\text{ V}$ | | | ± 0.5 | | |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = -20\text{ V}, V_{GS} = 0\text{ V}$ | | | -1 | | |
| | | $V_{DS} = -20\text{ V}, V_{GS} = 0\text{ V}, T_J = 55\text{ }^\circ\text{C}$ | | | -10 | | |
| On-State Drain Current ^a | $I_{D(on)}$ | $V_{DS} \leq -5\text{ V}, V_{GS} = -4.5\text{ V}$ | -8 | | | A | |
| Drain-Source On-State Resistance ^a | $R_{DS(on)}$ | $V_{GS} = -4.5\text{ V}, I_D = -3.0\text{ A}$ | | 0.050 | 0.064 | Ω | |
| | | $V_{GS} = -2.5\text{ V}, I_D = -2.0\text{ A}$ | | 0.065 | 0.085 | | |
| | | $V_{GS} = -1.8\text{ V}, I_D = -1.0\text{ A}$ | | 0.090 | 0.110 | | |
| | | $V_{GS} = -1.5\text{ V}, I_D = -0.5\text{ A}$ | | 0.110 | 0.165 | | |
| Forward Transconductance ^a | g_{fs} | $V_{DS} = -10\text{ V}, I_D = -3.0\text{ A}$ | | 12 | | S | |
| Dynamic^b | | | | | | | |
| Total Gate Charge | Q_g | $V_{DS} = -10\text{ V}, V_{GS} = -8\text{ V}, I_D = -5.3\text{ A}$ | | 14 | 21 | nC | |
| Gate-Source Charge | | | Q_{gs} | $V_{DS} = -10\text{ V}, V_{GS} = -4.5\text{ V}, I_D = -5.3\text{ A}$ | 7.6 | | 12 |
| Gate-Drain Charge | | | | | Q_{gd} | | 0.8 |
| Gate Resistance | R_g | $f = 1\text{ MHz}$ | 0.4 | 2 | 4 | k Ω | |
| Turn-On Delay Time | $t_{d(on)}$ | $V_{DD} = -10\text{ V}, R_L = 2.3\text{ }\Omega$ $I_D \cong -4.3\text{ A}, V_{GEN} = -4.5\text{ V}, R_g = 1\text{ }\Omega$ | | 0.20 | 0.3 | μs | |
| Rise Time | t_r | | | 1.00 | 1.50 | | |
| Turn-Off Delay Time | $t_{d(off)}$ | | | 4.00 | 6.00 | | |
| Fall Time | t_f | | | 2.00 | 3.00 | | |
| Turn-On Delay Time | $t_{d(on)}$ | $V_{DD} = -10\text{ V}, R_L = 2.3\text{ }\Omega$ $I_D \cong -4.3\text{ A}, V_{GEN} = -8\text{ V}, R_g = 1\text{ }\Omega$ | | 0.09 | 0.14 | | |
| Rise Time | t_r | | | 0.40 | 0.60 | | |
| Turn-Off Delay Time | $t_{d(off)}$ | | | 5.20 | 7.80 | | |
| Fall Time | t_f | | | 2.30 | 3.50 | | |
| Drain-Source Body Diode Characteristics | | | | | | | |
| Continuous Source-Drain Diode Current | I_S | $T_C = 25\text{ }^\circ\text{C}$ | | | -2.0 | A | |
| Pulse Diode Forward Current | I_{SM} | | | | -8 | | |
| Body Diode Voltage | V_{SD} | $I_S = -3\text{ A}, V_{GS} = 0\text{ V}$ | | -0.8 | -1.2 | V | |
| Body Diode Reverse Recovery Time | t_{rr} | $I_F = -3\text{ A}, dI/dt = 100\text{ A}/\mu\text{s}, T_J = 25\text{ }^\circ\text{C}$ | | 30 | 60 | ns | |
| Body Diode Reverse Recovery Charge | Q_{rr} | | | 20 | 40 | nC | |
| Reverse Recovery Fall Time | t_a | | | 13 | | ns | |
| Reverse Recovery Rise Time | t_b | | | 17 | | | |

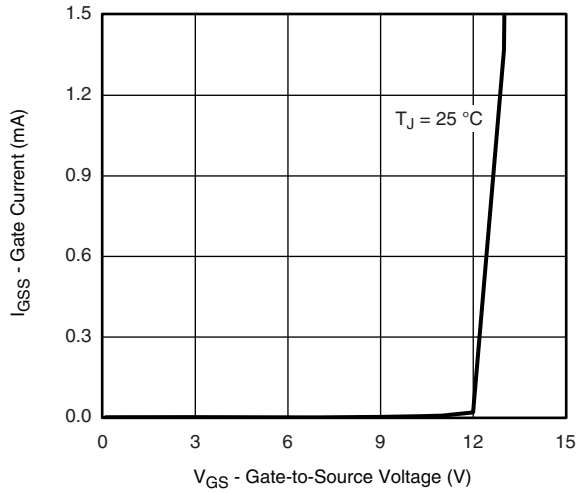
Notes:

- a. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$.
b. Guaranteed by design, not subject to production testing.

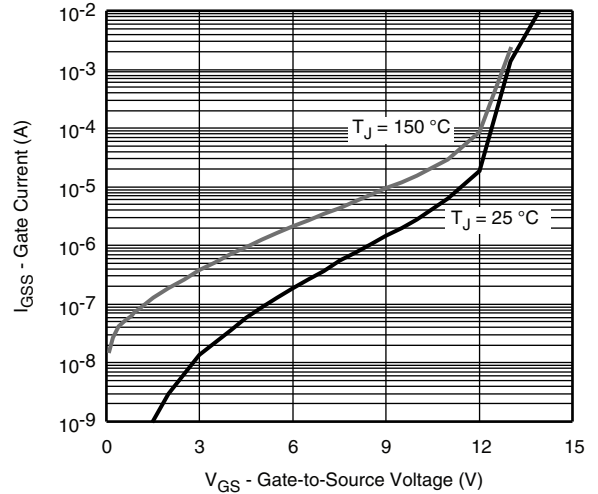
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



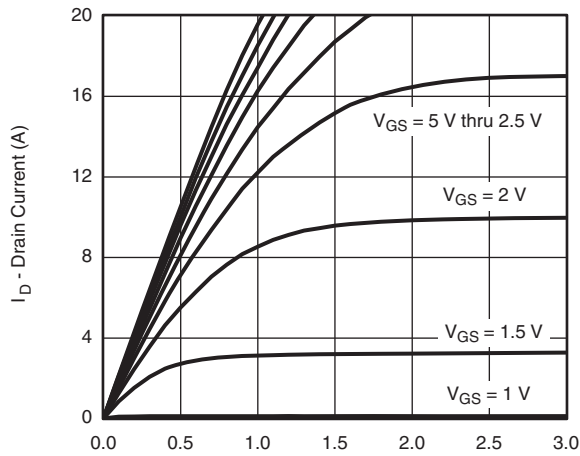
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



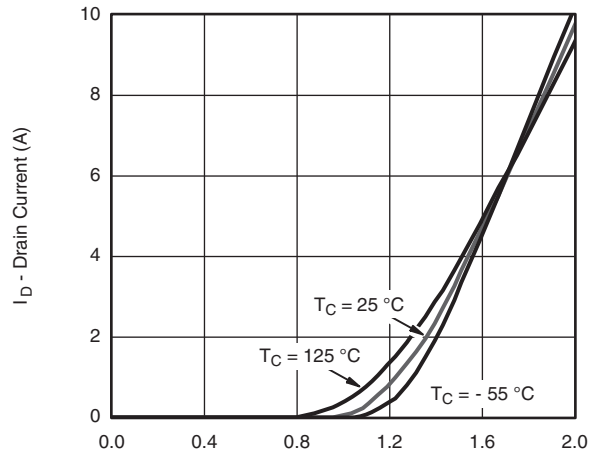
Gate Current vs. Gate-Source Voltage



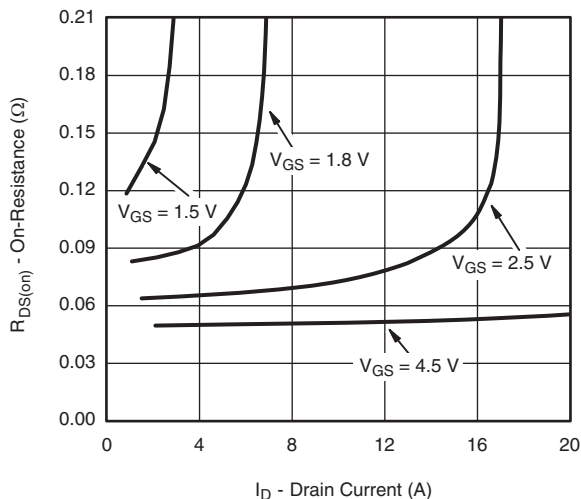
Gate Current vs. Gate-Source Voltage



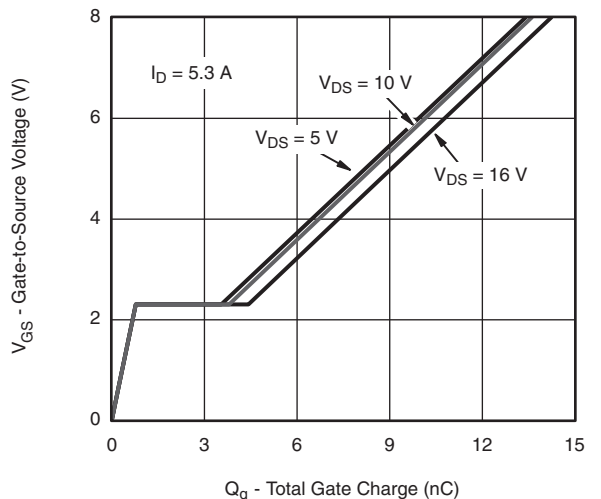
Output Characteristics



Transfer Characteristics



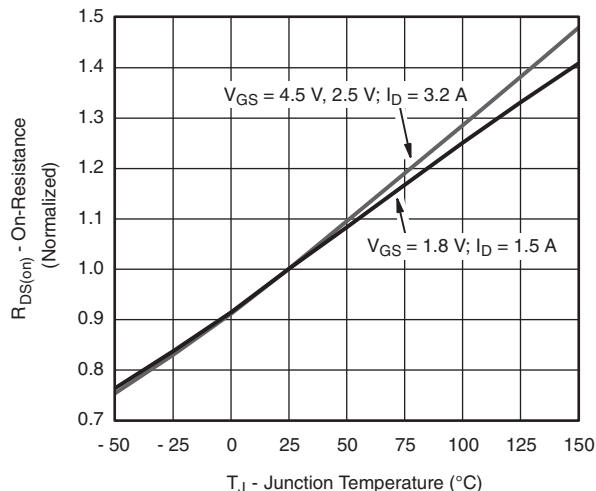
On-Resistance vs. Drain Current



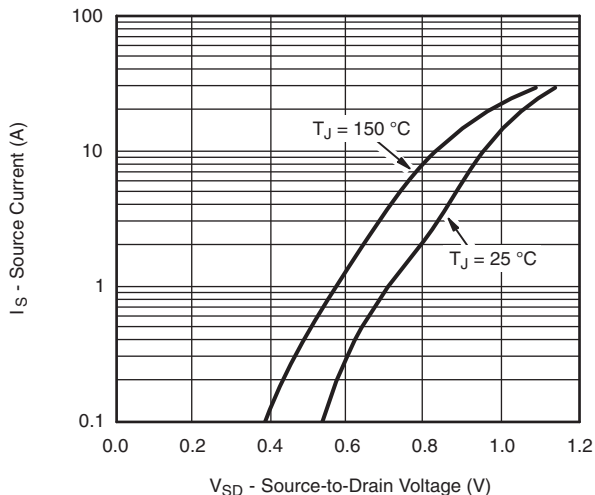
Gate Charge



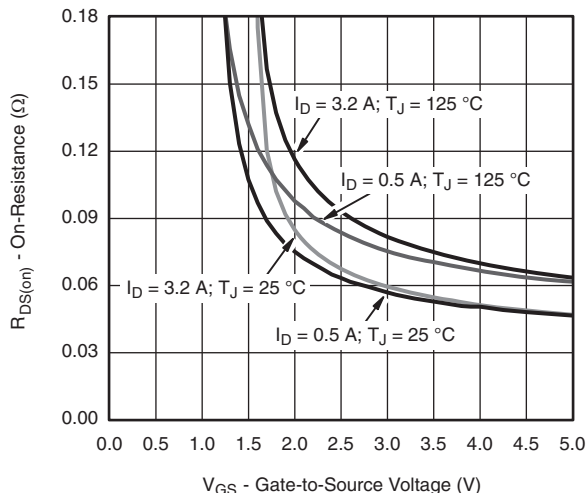
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



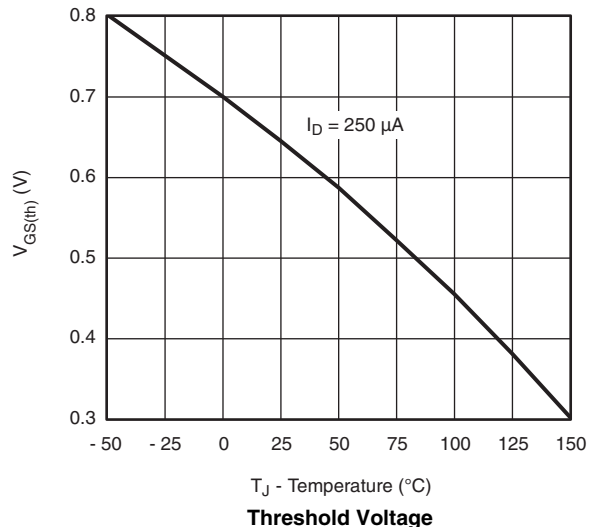
On-Resistance vs. Junction Temperature



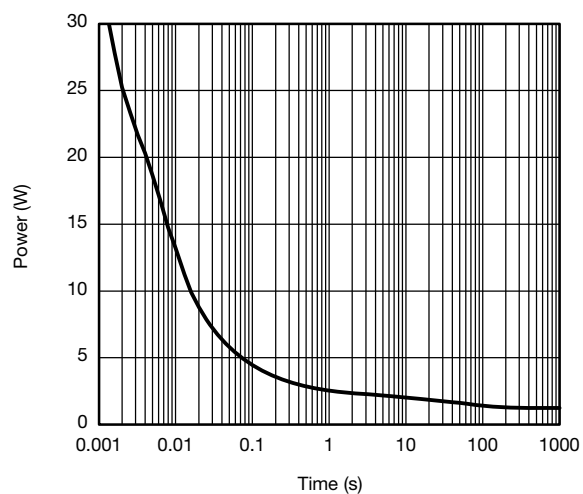
Source-Drain Diode Forward Voltage



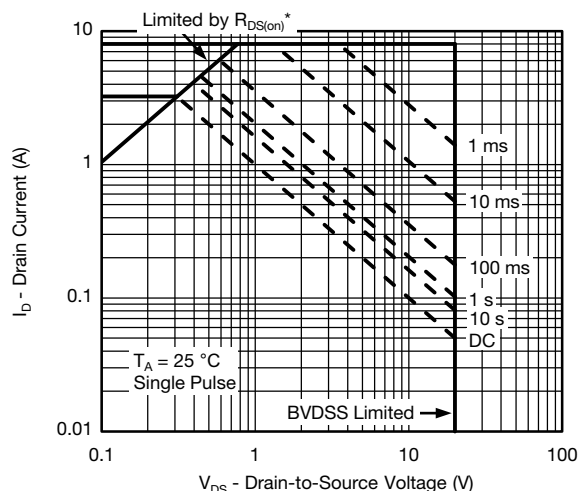
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



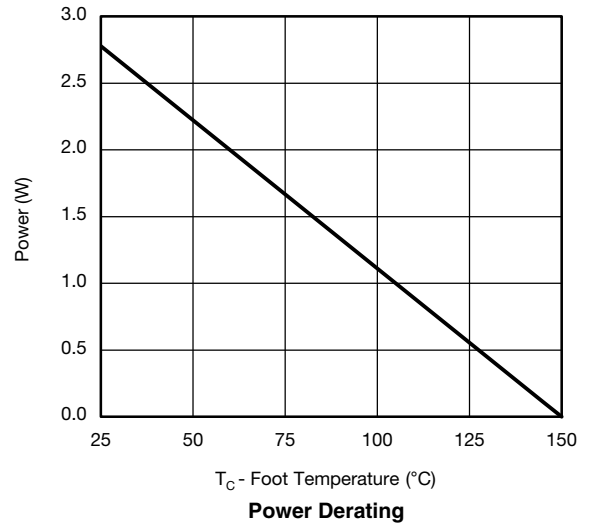
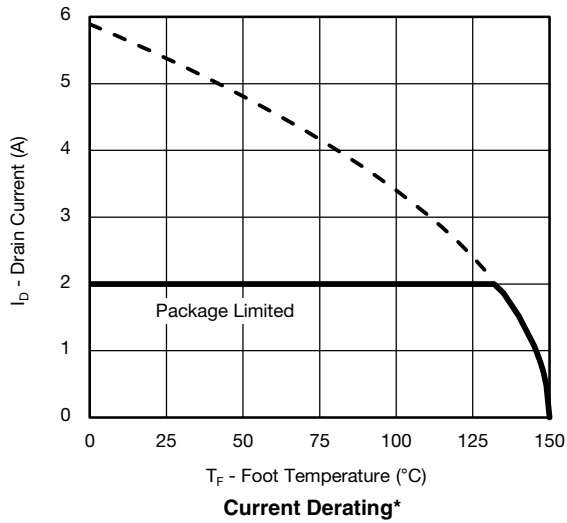
Single Pulse Power, Junction-to-Ambient



Safe Operating Area, Junction-to-Ambient

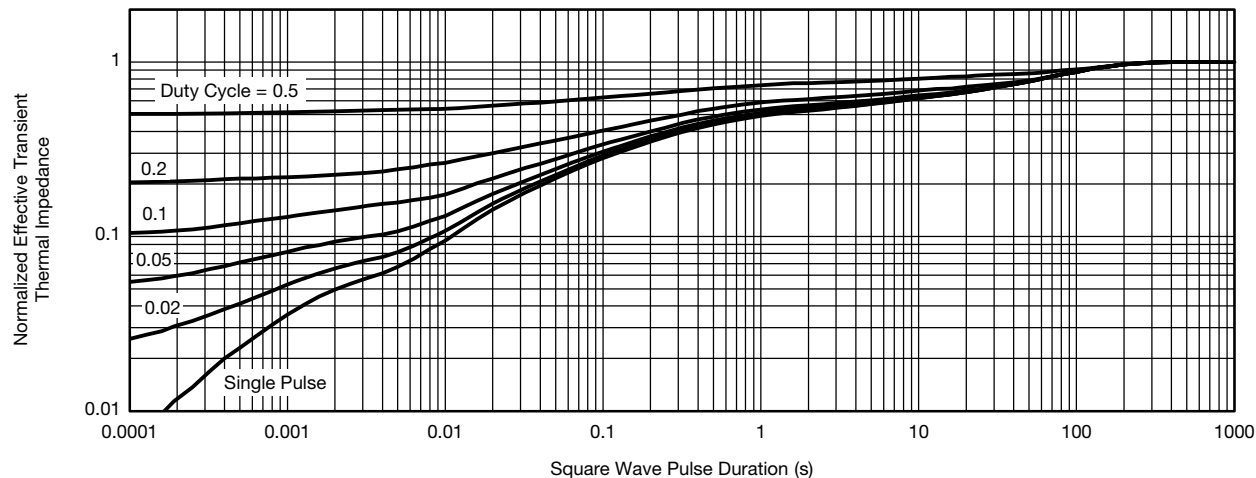


TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

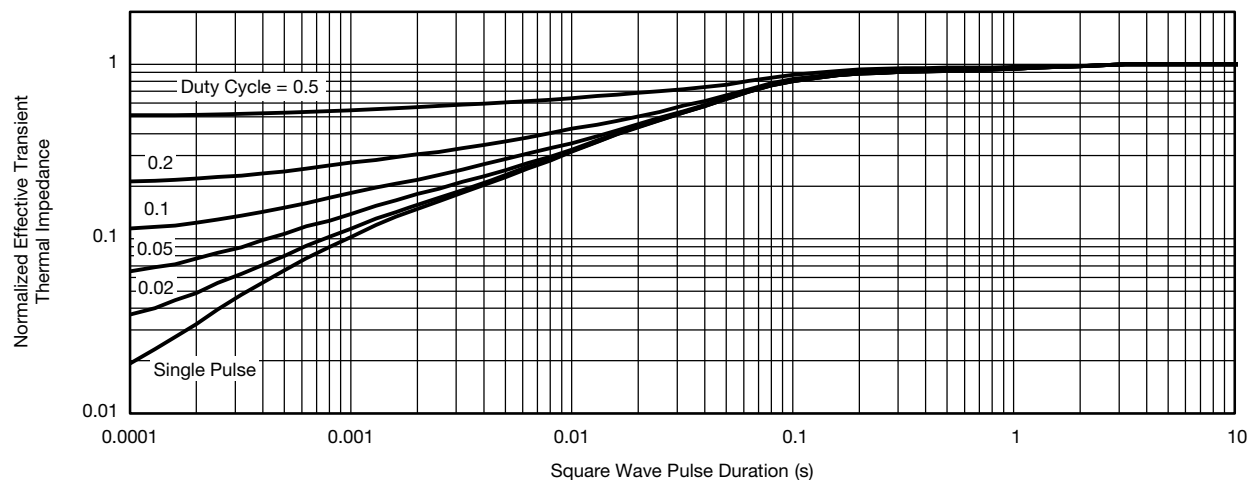


* The power dissipation P_D is based on $T_{J(max)} = 150\text{ °C}$, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient

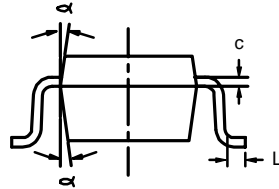


Normalized Thermal Transient Impedance, Junction-to-Foot

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SC-70: 6-LEADS



| Dim | MILLIMETERS | | | INCHES | | |
|----------------|-------------|------|------|----------|-------|-------|
| | Min | Nom | Max | Min | Nom | Max |
| A | 0.90 | - | 1.10 | 0.035 | - | 0.043 |
| A ₁ | - | - | 0.10 | - | - | 0.004 |
| A ₂ | 0.80 | - | 1.00 | 0.031 | - | 0.039 |
| b | 0.15 | - | 0.30 | 0.006 | - | 0.012 |
| c | 0.10 | - | 0.25 | 0.004 | - | 0.010 |
| D | 1.80 | 2.00 | 2.20 | 0.071 | 0.079 | 0.087 |
| E | 1.80 | 2.10 | 2.40 | 0.071 | 0.083 | 0.094 |
| E ₁ | 1.15 | 1.25 | 1.35 | 0.045 | 0.049 | 0.053 |
| e | 0.65BSC | | | 0.026BSC | | |
| e ₁ | 1.20 | 1.30 | 1.40 | 0.047 | 0.051 | 0.055 |
| L | 0.10 | 0.20 | 0.30 | 0.004 | 0.008 | 0.012 |
| α | 7°Nom | | | 7°Nom | | |

ECN: S-03946—Rev. B, 09-Jul-01
DWG: 5550

Single-Channel LITTLE FOOT® SC-70 6-Pin MOSFET Copper Leadframe Version Recommended Pad Pattern and Thermal Performance

INTRODUCTION

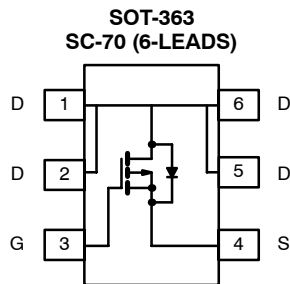
The new single 6-pin SC-70 package with a copper leadframe enables improved on-resistance values and enhanced thermal performance as compared to the existing 3-pin and 6-pin packages with Alloy 42 leadframes. These devices are intended for small to medium load applications where a miniaturized package is required. Devices in this package come in a range of on-resistance values, in n-channel and p-channel versions. This technical note discusses pin-outs, package outlines, pad patterns, evaluation board layout, and thermal performance for the single-channel version.

BASIC PAD PATTERNS

See Application Note 826, *Recommended Minimum Pad Patterns With Outline Drawing Access for Vishay Siliconix MOSFETs*, (<http://www.vishay.com/doc?72286>) for the basic pad layout and dimensions. These pad patterns are sufficient for the low to medium power applications for which this package is intended. Increasing the drain pad pattern yields a reduction in thermal resistance and is a preferred footprint. The availability of four drain leads rather than the traditional single drain lead allows a better thermal path from the package to the PCB and external environment.

PIN-OUT

Figure 1 shows the pin-out description and Pin 1 identification. The pin-out of this device allows the use of four pins as drain leads, which helps to reduce on-resistance and junction-to-ambient thermal resistance.



Top View

FIGURE 1.

For package dimensions see outline drawing SC-70 (6-Leads) (<http://www.vishay.com/doc?71154>)

EVALUATION BOARDS — SINGLE SC70-6

The evaluation board (EVB) measures 0.6 inches by 0.5 inches. The copper pad traces are the same as in Figure 2. The board allows examination from the outer pins to 6-pin DIP connections, permitting test sockets to be used in evaluation testing. See Figure 3.

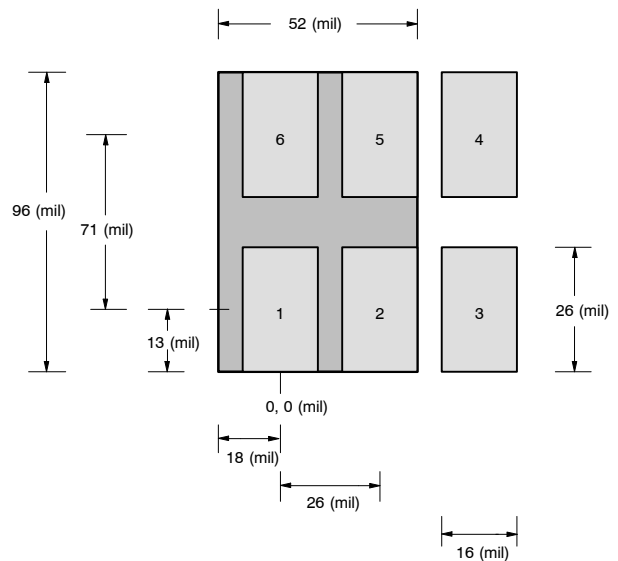


FIGURE 2. SC-70 (6 leads) Single

The thermal performance of the single 6-pin SC-70 has been measured on the EVB, comparing both the copper and Alloy 42 leadframes. This test was first conducted on the traditional Alloy 42 leadframe and was then repeated using the 1-inch² PCB with dual-side copper coating.

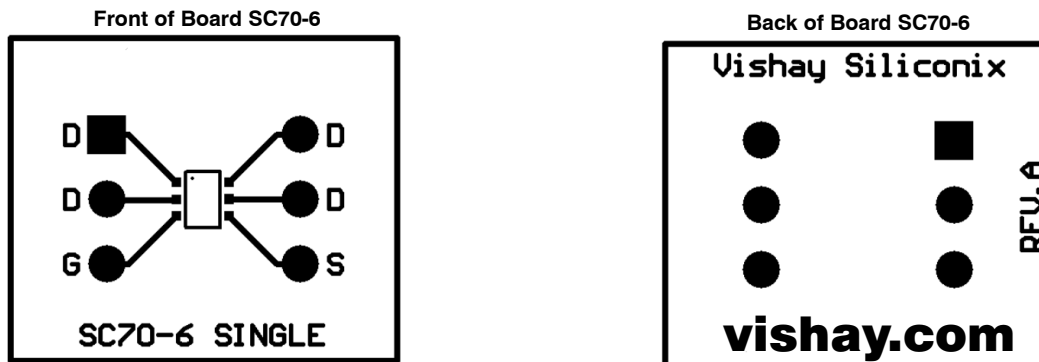


FIGURE 3.

THERMAL PERFORMANCE

Junction-to-Foot Thermal Resistance (Package Performance)

The junction to foot thermal resistance is a useful method of comparing different packages thermal performance.

A helpful way of presenting the thermal performance of the 6-Pin SC-70 copper leadframe device is to compare it to the traditional Alloy 42 version.

Thermal performance for the 6-pin SC-70 measured as junction-to-foot thermal resistance, where the “foot” is the drain lead of the device at the bottom where it meets the PCB. The junction-to-foot thermal resistance is typically 40°C/W in the copper leadframe and 163°C/W in the Alloy 42 leadframe — a four-fold improvement. This improved performance is obtained by the enhanced thermal conductivity of copper over Alloy 42.

Power Dissipation

The typical $R\theta_{JA}$ for the single 6-pin SC-70 with copper leadframe is 103°C/W steady-state, compared with 212°C/W for the Alloy 42 version. The figures are based on the 1-inch² FR4 test board. The following example shows how the thermal resistance impacts power dissipation for the two different leadframes at varying ambient temperatures.

| ALLOY 42 LEADFRAME | |
|--|--|
| Room Ambient 25 °C | Elevated Ambient 60 °C |
| $P_D = \frac{T_{J(max)} - T_A}{R\theta_{JA}}$ | $P_D = \frac{T_{J(max)} - T_A}{R\theta_{JA}}$ |
| $P_D = \frac{150^\circ\text{C} - 25^\circ\text{C}}{212^\circ\text{C/W}}$ | $P_D = \frac{150^\circ\text{C} - 25^\circ\text{C}}{212^\circ\text{C/W}}$ |
| $P_D = 590 \text{ mW}$ | $P_D = 425 \text{ mW}$ |

| COOPER LEADFRAME | |
|--|--|
| Room Ambient 25 °C | Elevated Ambient 60 °C |
| $P_D = \frac{T_{J(max)} - T_A}{R\theta_{JA}}$ | $P_D = \frac{T_{J(max)} - T_A}{R\theta_{JA}}$ |
| $P_D = \frac{150^\circ\text{C} - 25^\circ\text{C}}{124^\circ\text{C/W}}$ | $P_D = \frac{150^\circ\text{C} - 60^\circ\text{C}}{124^\circ\text{C/W}}$ |
| $P_D = 1.01 \text{ W}$ | $P_D = 726 \text{ mW}$ |

As can be seen from the calculations above, the compact 6-pin SC-70 copper leadframe LITTLE FOOT power MOSFET can handle up to 1 W under the stated conditions.

Testing

To further aid comparison of copper and Alloy 42 leadframes, Figure 5 illustrates single-channel 6-pin SC-70 thermal performance on two different board sizes and two different pad patterns. The measured steady-state values of $R\theta_{JA}$ for the two leadframes are as follows:

| LITTLE FOOT 6-PIN SC-70 | | |
|--|-----------|-----------|
| | Alloy 42 | Copper |
| 1) Minimum recommended pad pattern on the EVB board V (see Figure 3). | 329.7°C/W | 208.5°C/W |
| 2) Industry standard 1-inch ² PCB with maximum copper both sides. | 211.8°C/W | 103.5°C/W |

The results indicate that designers can reduce thermal resistance ($R\theta_{JA}$) by 36% simply by using the copper leadframe device rather than the Alloy 42 version. In this example, a 121°C/W reduction was achieved without an increase in board area. If increasing in board size is feasible, a further 105°C/W reduction could be obtained by utilizing a 1-inch² square PCB area.

The copper leadframe versions have the following suffix:

Single: Si14xxEDH
 Dual: Si19xxEDH
 Complementary: Si15xxEDH

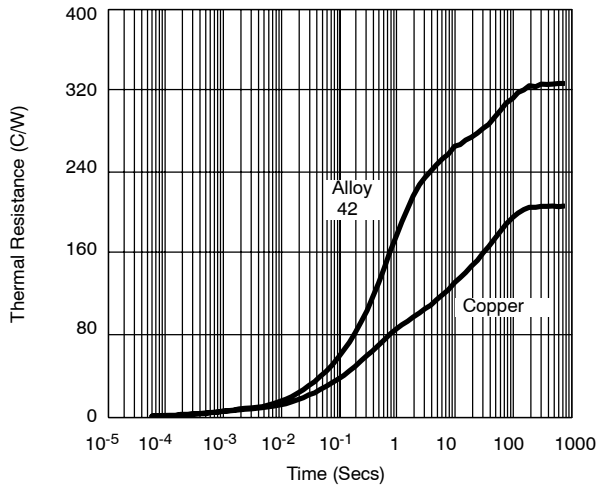


FIGURE 4. Leadframe Comparison on EVB

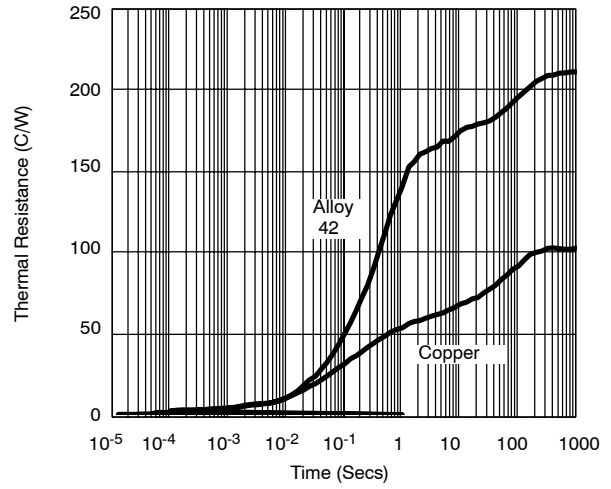
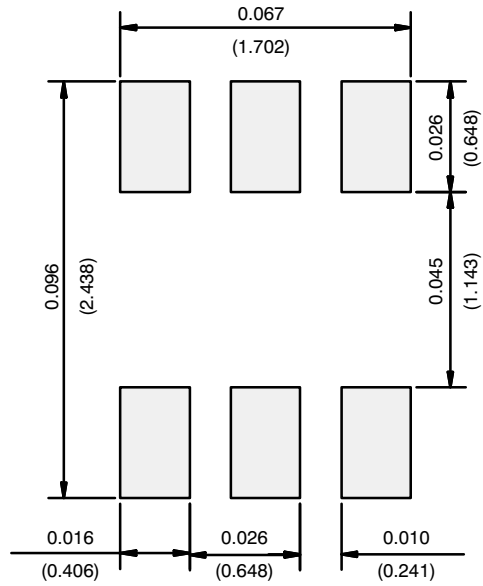


FIGURE 5. Leadframe Comparison on Alloy 42 1-inch² PCB

RECOMMENDED MINIMUM PADS FOR SC-70: 6-Lead



Recommended Minimum Pads
Dimensions in Inches/(mm)

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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

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Наши преимущества:

- Поставка оригинальных импортных электронных компонентов напрямую с производств Америки, Европы и Азии, а так же с крупнейших складов мира;
- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «JONHON», а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «FORSTAR».



JONHON

«JONHON» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели, кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



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